Electro Optical Components, Inc. EOC Click to go to 5464 Skylane Boulevard, Suite D, Santa Rosa, CA 95403 Product Selector Toll Free: 855-EOC-6300 info@eoc-inc.com www.eoc-inc.com LED Mid-Infrared (MIR) Photodiode 2.6 - 4.6 μm Series with a glass cover Microsensor NT Lms43PD-05-CG series Value Symbol Units **Device parameters** d 0,5 Sensitive area diameter mm Storage temperature T_{stg} 0..+50 °C Operating temperature 0..+50 °C T_{opr} Lead soldering temperature °C +180 $\mathsf{T}_{\mathsf{sol}}$ (time < 3 seconds, 3 mm from case) Reverse voltage Vr 0.1 V

| Photodiode parameters | Conditions | Symbol | Value | Units |
|-------------------------------|---|-----------------|-----------|-------|
| Cut-off wavelength | T = 25 °C | λ_{cut} | 4.5 - 4.8 | μm |
| Max. sensitivity range (>80%) | T = 25 °C | λ_p | 3.5 - 4.2 | μm |
| Dark current | T = 25 °C; V _{reverse} = 0.1 V | I _d | 8 - 25 | mA |
| Shunt resistance | T = 25 °C; $V_{reverse}$ = 10 mV | R _{sh} | 4 - 6 | Ω |
| Capacitance | T = 25 °C; $\lambda = \lambda_p$ | С | | pF |
| Capacitance | $T = 25 °C; \lambda = \lambda_p$ | C | | pF |

All specifications are for photodiode operation at 25°C unless otherwise stated

Photodiodes Lms43PD-05-CG series are fabricated from narrow band-gap InAsSbP/InAs-based heterostructures lattice matched to InAs substrate.

Photodiode with a glass cover provides a signal that is minimum 3 times higher than the signal from the same photodiode without a glass cover due to:

- increase of the photodiode effective sensitive area with a glass cover
- increase of the emission got inside the PD crystal





Mid-Infrared (MIR) Photodiode

2.6 - 4.6 μm

Series with a glass cover

Lms43PD-05-CG series

| Packages | Model |
|--|-----------------------|
| TO-18 with a glass covering | Lms MIR PD-05-CG |
| PD with a built-in preamplifier; TO-18 with a glass covering and a parabolic reflector without a window in an aluminium tube | Lms MIR PD-05-CG-R-PA |

Recommended modes of PD operation

PD used as a current source (photovoltaic mode)

PD used in a photoconductive mode (under reverse bias)





We recommend using **photovoltaic mode**, when PD is used under no reverse bias. Use photoconductive mode (mode with reverse bias) with caution.

IMPORTANT CAUTIONS:

- check your connection circuit before turning on the PD;
- mind the PD polarity: PD anode is marked with a RED dot;
- do not connect the PD to the multimeter;
- do not touch the glass covering and do not apply any force to it;
- observe the allowable operating temperature range, exceeding this eange may cause irreparable damage of the glass cover

Related products:

- LEDs sources of mid-infrared radiation;
- **SDM** synchronous detector for PD models with preamplifiers Lms MIR PD-XX-CG-R-PA. SDM synchronous detector measures the voltage signal from the output of photodiode preamplifier and converts it to the DC voltage signal proportional to amplitude of voltage from input.



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Series with a glass cover

2.6 - 4.6 μm

Lms43PD-05-CG series

Technical Drawing

Lms MIR PD-05-CG





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Connections:

The output of PD with a built-in preamplifier has four wires:

- "+" power input (to the "+" of the power output terminal block of the SDM synchronous detector);
- "-" power input (to the "-" of the power output terminal block of the SDM synchronous detector);
- output photodiode signal (to the "-" of the signal input terminal block of the SDM synchronous detector);
- output photodiode signal (to the "+" of the signal input terminal block of the SDM synchronous detector).

For the proper connection mind colours of the wires pointed in the technical data provided with the photodiode.